

Actuation of MEMS Devices using Radiation Pressure

Rafael Kleiman, McMaster University Hamilton, Ontario, Canada Ho Bun Chan, University of Florida John Garno, JPG Design, New Jersey

Panamerican Advanced Studies Institute MicroElectroMechanical Systems San Carlos de Bariloche, Patagonia, Argentina 21-30 June 2004



- Lucent Technologies, Bell Laboratories
- CFI Canadian Foundation for Innovation
- OIT Ontario Innovation Trust
- NSERC National Science and Engineering Research Council
- CRC Canada Research Chairs Program





- Optics and Photonics
- RF, Microwave, and Telecommunication Applications
- Micromachining Technologies and Facilities
- Microfluidics (Biomedical, Chemical Sensor Systems, Micro Test Analysis Systems)
 Sensors, Actuators, and Microrobotics
- CAD, Modeling, and Simulation
- Testing and Test Structures

Source: CMC – Canadian Manufacturing Corporation

MEMS Activities in Canada



Universities

- Simon Fraser University (BC)
- University of Alberta (AB)
- University of Calgary (AB)
- University of Saskatchewan (SK)
- University of Manitoba (MB)
- Carleton University (ON)
- McMaster University (ON)
- Queen's University (ON)
- University of Toronto (ON)
- University of Waterloo (ON)
- University of Western Ontario (ON)
- University of Windsor (ON)
- Concordia University (QC)
- École Polytechnique de Montréal (QC)
- McGill University (QC)
- Dalhousie University (NS)

National Labs and Consortia

- Canadian Manufacturing Corporation
- Communications Research Centre
- INO, Photonic Materials and Processes
- National Research Council / Institute for Microstructural Sciences
- Photonics Research Ontario

Corporations

- Bookham Technology
- Centre for Large Space Structures and Systems CLS3 Inc.
- COM DEV Ltd., R&D department
- DALSA Semiconductor
- Infolytica Corporation
- Integrated Engineering Software Sales Inc.
- i-STAT Corp
- JDS Uniphase Corporation, R&D (Strategic Research)
- Medtronic of Canada Limited
- Micralyne Inc.
- Optenia
- SUSS MicroTec, Inc.
- Umech Technologies, LLC
- Xerox Research of Canada

Source: CMC – Canadian Manufacturing Corporation



MEMS Activities at McMaster

- Radiation pressure experiments (1)
- Ultra-low-force Sensor development (1)
- MEMS integrated optics (2)
- III-V MEMS devices and systems (1)
- Adaptive Optics (1)
- Laser micromachining for new materials (2)
- "nanopower" for ubiquitous sensing (1)
- Communication to ubiquitous sensors (2)
- Novel microfluidic applications (2)
- Biomedical applications (3)

CEMD – Research Fabrication facility BIMR – Materials and Characterization HHS – Medical School and research on campus



Outline

Motivation Background:

- history of radiation pressure experiments
- laser tweezer experiments
- Radiation pressure vs. thermal effects Measurement system/Experimental design Measurement theory/Circuitry Present Data
- Conclusions



- Connection to optical tweezer experiments
- Understand role of radiation pressure in Optical MEMS devices
- Study physics of Casimir effect using real photons instead of virtual ones – allows the effects to be controlled and studied, including spectroscopically
- Study and utilize plasmon effects to generate enhanced forces on MEMS devices
- Framework for implementing optical computing
- Framework for studying macroscopic quantum entanglement

Radiation Pressure Experiments

A brief history of radiation pressure experiments:

- 1864 Maxwell, pressure on reflection = 2I/c
- 1873 Sir William Crookes "Crookes's Radiometer", turns the wrong way for radiation pressure (Maxwell refereed the paper)
- dark side hotter than shiny side → more pressure, Maxwell showed this is incorrect, just heat flow
- 1879 Reynolds submitted paper on "thermal transpiration", flow of gas through porous plates with ΔT , Maxwell refereed it, liked the ideas but not the math
- 1879 Maxwell submitted "On stresses in rarified gases arising from inequalities in temperature", crediting Reynolds, and then died
- 1881 Reynolds paper was published
- 1901 P. Lebedev, and E. Nichols & G. Hull, measure radiation pressure in better vacuums





"Light mill", "solar radiometer"



Laser Trapping/Laser Tweezers

McMaster

Ashkin, et al, at Bell Labs

- 1970: 2-d trapping of latex spheres in water
- 1970: 3d trapping in counter-propagating beams
- 1986: single beam 3-d trapping of atoms...
- 1987-9: application to Biology begins...
- 3 perspectives on trapping:
 - force: refraction/ray tracing
 - energy
 - E field gradients







All Optical Devices?



- Switching one light beam with another light beam
- Optical computing (perhaps for network)
- Rough comparison to other non-linear media:

$$\begin{split} n &= n_0 + n'_2 |E|^2 \qquad n'_2 \sim 1.5 \chi^{(3)} / \epsilon_0 n_0 \\ \Delta n/n_0 &= (n'_2/n_0) |E|^2 \\ n'_2/n_0 \sim 3.7 \times 10^{-23} \text{ m}^2/\text{V}^2, \text{ for SiO}_2 \\ n'_2/n_0 \sim 3.6 \times 10^{-22} \text{ m}^2/\text{V}^2, \text{ for CS}_2 \\ \Delta \theta &= P_{\text{rad}} A/kl = (\epsilon/\text{Y}) |E|^2 \quad \text{optimally} \\ \epsilon/\text{Y} \sim 1.3 \times 10^{-22} \text{ m}^2/\text{V}^2, \text{ for Si/polystyrene} \\ enhance the effect and make devices smaller/faster \end{split}$$

gets interesting

• If



Why not just use thermal effects? How to separate the effects?

Big parasitic effect that raises a multitude of strategies/design issues

- reduce exposure of metals/semiconductors/absorbing materials
- pull heat away (by increasing coupling to outside)
- design to minimize thermal gradients
- choose wavelength/ materials correctly
- design to go with it (reduce coupling to mode of interest)
- work at frequencies above (thermal time constant)⁻¹

Reduce coupling to torsional mode?







- MEMS device is actuator (and sensor)
- Glue dielectric sphere to MEMS device

 to mimic laser tweezer experiments
 (functionally equivalent to a 1-d trap)

 to minimize heating effects
- Optical design/layout
- HV chamber and vibration isolation
- Low-noise circuitry

MEMS Force Sensor





H. B. Chan, V. A. Aksyuk, R. N. Kleiman, D. J. Bishop, and Federico Capasso, Science, 291, 1941 (2001).

Experimental Layout - Force sensor



Experimental Layout - Optics



Circuitry for dc Detection

Capacitive detection of torsional motion



For small θ ,

 $\propto \Delta C$

 V_{signal}

 $\propto \Lambda F$

 $\propto \theta$

dc Capacitance Shift







- Thermal noise of detector from e_n of input transistor; flat *vs*. frequency
- Thermal noise of oscillator peaked at resonance:

 $f_n \sim (4k_{\rm B}TkQ/\omega_0)^{1/2}$

• But signal increases by Q at resonance

 $f_n' \sim (4k_BTk/Q\omega_0)^{1/2}$

- .:. Signal to noise generally improves at resonance
- Want low k, high ω_0 , high Q:

ideal direction for MEMS

Circuitry for ac Detection



Can drive the oscillator electrically or optically and use demodulation circuitry to measure ac components with ~ 10 kHz BW



Frequency Dependence

oscillator amplitude (~ X 10⁻⁸m)

10



et

NA IE

Frequency (Hz)

Circuitry for Resonant Detection



Modulate force at resonant frequency of torsional oscillator



Resonant Amplitude





Potential Energy





Radial Force





X Axis

x-component of Force



laster

University

WERE

X Axis

Resonant Amplitude





Polarization Dependence and Anisotropy Effects



Total force, F, on a piece of polarized dielectric:

 $\mathbf{F} = \int (P \cdot \nabla) \mathbf{E} \, \mathrm{dV}$

For a *linear and isotropic* dielectric:

 $\mathbf{P} = \mathbf{\varepsilon}_0 \mathbf{\chi} \mathbf{E}$



 $(\mathbf{P} \bullet \nabla) \mathbf{E} = \frac{1}{2} \varepsilon_0 \chi \nabla(\mathbf{E}^2)$

If $\mathbf{P} \neq \varepsilon_0 \chi \mathbf{E}$, then force is not radially symmetric Related to torques observed on asymmetric objects

Quantitative Results

- McMaster
- Thermal time constant ~ 35 ms conduction through rods + some radiative coupling
- 4 methods for calibrating optical force: detection electronics, electrical drive, thermal noise of oscillator (equivalent to method used for tweezers), detector noise
- Displacement noise: $x_n = 2.0 \text{ pm/Hz}^{1/2} \text{ off resonance}$
- Force noise: $f_n = 6.0 \text{ pN/Hz}^{1/2}$ off resonance
- Equivalent noise: $f_n' = 0.017 \text{ pN/Hz}^{1/2}$ on resonance
- Displacement ~ 4.4 pm at dc, 110 nm at resonance, 3 mW
- Force experimentally observed: F = 0.26 pN/mW ± many systematic checks
- Force theoretically expected:

 $F \sim 0.06/c = 0.20 \ pN/mW \pm detailed calculations$

• Anisotropy (~3:1), some idea why, interesting in itself



Convincing evidence of radiation pressure on a dielectric sphere:

- numbers are reasonable
- separation of thermal effects from radiation pressure by examining the frequency dependence
- spatial variation is reasonable

See anisotropy/polarization effects in present device Better S/N by working at resonance (~ $0.017 \text{ pN/H} \pm^2$) Significant actuation of the MEMS device (110 nm) With enhancements and optimization \checkmark potential for interesting all-optical devices